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The effective mass and the *g*-factor of the strongly-correlated 2-D electron fluid. Evidence for a coupled-valley state in the Si system.

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PACS. 05.30.Fk – First pacs description. PACS. 71.27.+a – Second pacs description. PACS. 71.45.Gm – Third pacs description.

Abstract. – The effective mass m^* , and the Landé g-factor of the uniform 2-D electron system (2DES) are calculated as a function of the spin polarization ζ , and the density parameter r_s , using a non-perturbative analytic approach. Our theory is in good accord with the susceptibility data for the simple 2DES, and in excellent agreement with the two-valley Si-2DES data of Shashkin et al. While g^* is enhanced in GaAs, m^* is enhanced in Si. The two-valley susceptibility is treated within a coupled-mode (coupled-valley) approach. The coupled-valley model is confirmed by comparison with the Quantum Monte Carlo results for a 4-component 2DES.

The 2-D electron fluid (2DES) exhibits a wealth of intriguing physics, straddling a rich phase diagram [1,2]. The phase diagram contains spin-polarized states at sufficiently large r_s , say $\sim 20-27$. Here $r_s = (\pi n)^{-1/2}$ is the electron-disk radius [3,4] at the density n, in atomic units. It is also equal to the value of the coupling constant $\Gamma = (\text{potential energy})/(\text{kinetic}$ energy). The intermediate regime $r_s \sim 5-20$ also hosts many ill-understood phenomena including the metal-insulator transition (MIT) [5]. Anomalous values (e.g, see [6]), of g^* and m^* have been found. Some experiments suggest that an enhancement of g^* is responsible for the strong enhancement of m^*g^* , while results [7] on Si metal-oxide field effect transistors (MOSFETs) suggest that it is m^* , and not g^* which is enhanced. In this study we show that, for ideally thin 2-D layers. g^* is enhanced in GaAs-like systems, while m^* is enhanced in Si-like multi-valley systems. The existence of a coupled-valley state follows naturally from the physics of the Si system, and here we present a model leading to excellent quantitative agreement with experiment, and with Quantum Monte Carlo (QMC) simulations of a 4-component 2DES [8].

Fermi liquid-type theories [9] are valid for $r_s < 1$. Such perturbative methods have been applied, invoking impurities [10], or charge and spin-density wave effects [11]. On the other hand, QMC calculations of m^* involve the *excited states* of the 2DES and are less reliable than for the ground state. QMC results up to $r_s = 5$ have been reported [12].

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We showed recently that the 2-DES, 3-DES, and dense hydrogen can be studied using a mapping to a classical fluid [13–16]. The accuracy of the map was established by comparison with QMC and other independent calculations. Here we use this classical map to evaluate m^* and g^* for the low-density 2-DES. The method is best understood within a density-functional picture.

The density-functional perspective. The Hohenberg-Kohn-Mermin theorem asserts that the Helmholtz free energy F is a minimum at the true density [17]. If n(r) is the true density, it obeys the variational equation $\delta F[n(r)]/\delta n(r) = 0$. If the origin of coordinates is on an electron, then if n(r) is the density as seen from this electron, it is a *pair-density* such that n(r) = n g(r). Here g(r) is the electron-pair distribution function (PDF). The variational condition gives the Kohn-Sham (KS) equation as usual. Then n(r) is obtained via a sum over the KS orbital-densities $|\psi_i|^2$ weighted by the Fermi factors f_i . If the electrons formed a classical system, the variational equation becomes the Boltzmann form for the density:

$$n(r) = ne^{-\beta \{V_{cou}(r) + V_p(r) + V_c(r)\}}.$$
(1)

 $V_{cou}(r)$ is the Coulomb interaction between the electron at the origin and the electron located at \vec{r} . Similarly, $V_p(r)$ is the Poisson potential at \vec{r} , and $V_c(r)$ is a correlation potential. For a classical system the $V_{xc}(r)$ of standard KS theory is replaced by just a correlation potential $V_c(r)$. In effect,Eq. 1 evaluates the g(r) of the classical fluid. However, the g(r)of a classical fluid is accurately given by the hyper-netted chain (HNC) inclusive of a bridge function [18]. Thus, the extended HNC equation is a classical KS equation where $V_c(r)$ is the sum of HNC+bridge diagrams. The construction of the Bridge diagrams for the 2DES is given in refs. [15, 20].

The classical map has no exchange, and fails as $T \to 0$. We rectify these lacunae as follows. In a system *without* Coulomb interactions, g(r) should reduce to $g^0(r)$ which is known analytically (at T = 0) or numerically. The first step of the mapping is to introduce a potential $\phi_{ij}^0(r)$ (where i, j are spion labels) such that $\phi_{ij}^0(r)$ generates $g_{ij}^0(r)$ when used in the HNC equation for ideal electrons [19]. This leads to an exact treatment of exchange.

Electrons at T = 0 have kinetic energy. Hence the classical map of the quantum fluid at T = 0 would be at some "quantum temperature" T_q . This is determined by requiring the correlation energy ϵ_c of the classical fluid at T_q be equal to the ϵ_c of the quantum fluid at T = 0. This may be regarded as a "calibration" of the classical fluid to recover the quantum exchange-correlation energy in the r_s range of interest. Here we use the $\epsilon_c(r_s)$ given by QMC (Tanatar-Ceperley results for the fully spin-polarized 2DES for r_s up to 30 were used in [15]). Once T_q , which maps the T = 0 quantum fluid to a classical fluid is known, finite-T fluids are calculated from classical fluids at the temperature $T_{cf} = (T^2 + T_q^2)^{1/2}$, as justified in ref. [14]. We have shown [13, 15] that the classical PDFs are in very close agreement with the quantum fluid PDFs obtained via QMC. The success of the method(refs. [13–16]) for 2-D and 3-D electrons, hydrogen fluids, and for 4-component 2-D electron fluids as judged by comparison with QMC data establishes it to be a well controlled, highly reliable method. The PDFs are easily used in a coupling-constant integration for the exchange-correlation free energies F_{xc} . Our finite-T method accurately recovers the low-T logarithmic terms in F_c which cancel with corresponding terms in F_x . This method, based on a *classical* mapping of the quantum calculation to an HNC calculation is called CHNC [1, 13–15].

Evaluation of m^* and g^* . The evaluation of the susceptibility enhancement m^*g^* uses the T = 0 results for the exchange-correlation energy $\epsilon_{xc}(r_s, \zeta)$. This is expressed in terms of $\epsilon_{xc}(r_s, 0)$ and $\epsilon_{xc}(r_s, 1)$, and a polarization factor $P(r_s, \zeta)$ given in Eq. (6) of Ref. [15]. Using Hartree units, the ratio of the static spin susceptibility to the ideal (Pauli) spin susceptibility

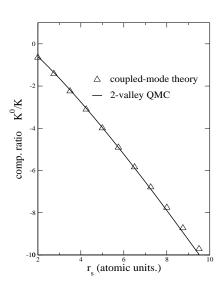


Fig. 1 – The compressibility ratio K^0/K calculated from the 4-component (2-valley) QMC results of Conti et al., and from the 2-component (1-valley) data using the $k \to 0$ limit of Π_0/Π_{cm} where Π_{cm} is the coupled-mode polarization function.

is:

$$\chi_P / \chi_s = (m^* g^*)^{-1} = 1 + r_s^2 \,\partial^2 \epsilon_{xc} / \partial \zeta^2.$$
⁽²⁾

The effective mass m^* at temperature T is the ratio of the specific heats, $C_v(T)/C_v^0(T)$ of the interacting and non-interacting 2DES.

$$m^*(T) = C_V(r_s, \zeta, T) / C_0(r_s, \zeta, T).$$
 (3)

The specific heats are obtained as the second-T derivatives of the interacting and ideal Helmholtz $F(r_s, T)$. Here T is the physical temperature and not T_{cf} . The latter is used only in the classical map to obtain the PDFs. $F_x(r_s, T)$ has a logarithmic term of the form $T^2 \log(T)$ which is cancelled by a similar term in $F_c(r_s, T)$. That is,

$$F_x = A_x + B_x t^2 \log(t) - C_x t^2, \ t = T/E_F$$
(4)

$$F_c = A_c + B_c t^2 \log(t) - C_x t^2, \ B_x = -B_c.$$
(5)

This cancellation holds to 85-95% in our numerical CHNC results, for the range $r_s = 5 - 30$, 0 < t < 0.25. Thus, at $r_s = 15$ and 25, (B_x, B_c) are (-0.0258, 0.0228), and (-0.0155, 0.0142). If Hubbard-type finite-*T* RPA were used in the self-energy, the cancellation is quite poor, even at low- r_s . These logarithmic terms and the m^* have also been studied by Geldart et al., using CHNC [21]. Multi-valley systems- Shashkin et al. [7], also [23], have studied clean low-density 2-valley 2DES in Si-MOSFETs. The two valleys are assumed degenerate [24]. It is found [7] that the m^* is strongly enhanced, while g^* shows little change. The enhanced m^* is independent of ζ . These results, "contrary to normal expectations", are reproduced by our coupled-mode theory of two valleys.

EUROPHYSICS LETTERS

Two equivalent valleys and two spins imply 10 different PDFs, g_{ij}^{uv} , where u, v are valley indices. Such a calculation for each r_s, ζ, T and many values of the coupling constant is laborious. A simpler procedure using just three PDFs is possible. Even if $\zeta \neq 0$, each valley has a density n/2. Thus the 2-valley system may be made up from the known properties of the one-valley (two-spin) 2DESs coupled together by their Coulomb interaction. The individual 1-valley correlation free energies F_c^u , F_c^v are known from QMC and CHNC results. The intervalley term for a system with a total density n, and valley densities n/2 is not known. Here we present a *simple approximation* validated by calculating the 2-valley compressibility in the same way and comparing with the QMC data of Conti et al [8]. There is no exchange interaction between up-spin and down-spin electrons in the one-valley system, and the spin densities are n/2 at $\zeta = 0$. Hence, since $F_c^u(n/2)$, $F_c^v(n/2)$, and $F_c(n, \zeta = 0, [g_{12}])$ for the one-valley system are known, we build up the 2-valley system within the assumption that $F_c(n, \zeta = 0)$ can be used for the inter-valley contribution to the F_c of the 4-component (i.e., 2-valley) system. In a full 4-component CHNC calculation, the inter-valley interaction is switched on via a coupling constant integration. This effect can be recovered within linear response by developing the coupled-mode 2-valley response functions. An analogous coupledmode problem arises in electron-hole systems (see Vashishta et al [22]).

The total (spin or charge) density-fluctuation spectrum of the electrons in a given (single) valley v is described by the response functions $\chi_v = \chi_v^0/D_v$, where χ_v^0 is the 2-D Lindhard function weighted appropriately with the square of the Bohr magneton μ_B or unity, and D_v is a corresponding denominator for each case. The Pauli susceptibility χ_P is the long-wavelength limit $\mu_B^2 \chi_v^0(k=0)$. Let us consider a denominator of a response function (which may be the charge response χ , the proper polarization function Π , or the spin susceptibility χ_s , depending on how the local-field factor G_v is specified). The denominator $D_v = 1 - v_{cou}(1 - G_v)\chi_v^0$ and defines G_v , the local-field factor (LFF, see [26]). We are only concerned with the static $k \to 0$ limit. Then G_v for Π are related to K^0/K , while the G_v for χ_s is given by χ_P/χ_s , as in Eq. 2, and depends on the correlation free energy F_c of the one-valley 2DES. When two such 2DESs, described by χ_v and χ_u interact via the inter-valley term, coupled modes are formed. These modes are described by the zeros of a new denominator of the response function of the total 2-valley system. This coupled-mode form is [22]:

$$\chi_{cm} = [\chi_u^0 + \chi_v^0 + v_{cou}^2 \chi_u^0 \chi_v^0 (\Sigma G_{uv})] / D_{cm}$$
(6)

$$\Sigma G_{uv} = G_u + G_v - G_{uv} - G_{vu} \tag{7}$$

$$D_{cm} = D_u D_v - v_{cou}^2 \chi_u^0 \chi_v^0 (1 - G_{uv}) (1 - G_{vu})$$
(8)

Here G_{uv} is an LFF arising from the inter-valley term F_{uv} already discussed, and modeled by $F_{12}(n, \zeta = 0)$ at k = 0. Hence we express the susceptibility enhancement χ_s/χ_P as χ_{cm}/χ_P , and this is evaluated from the G_u, G_v and G_{uv} . Equation 2 determines $G_u = G_v$, where the correlation part involves the second derivative $(r_{sv}^2 d^2 F_c^v/d\zeta^2)$. Similarly the cross term G_{uv} involves $r_s^2 d^2 F_{12}^c(n, \zeta = 0)/d\zeta^2$. The 4-component QMC results of Ref. [8] for $F_c(r_s, \zeta = 0, T = 0)$ enable us to calculate the compressibility ratio K^0/K of the 2-valley system directly. The coupled-mode theory, applied to the proper polarization function II gives another evaluation K^0/K . The agreement between the two methods is shown in Fig. 1. A similar comparison for χ_P/χ_s is not possible as the QMC results are available only at $\zeta = 0$. However, the agreement between the two estimates of K^0/K validates our coupledmode evaluation of 2-valley properties from the 1-valley energies. Thus the 2-valley results are constructed from the 1-valley CHNC energies (which argee closely with QMC data) which include the usual bridge contributions [15].

Results-In Fig. 2 we show $\chi_s/\chi_P = m^*g^*$ for a single-valley system, as a function of the

density n, and as a function of r_s (see [3]) at T = 0 for $\zeta = 0$. Our results, the experimental data of Zhu et al. [6], and QMC data, extracted from Fig. 2 of ref. [2] are displayed. The high density regime [27] is in agreement with standard theories and is not displayed.

For the Zhu et al. data we use their fitted form $m^*g^* = (2.73 + 3.9 n \zeta) n^{-0.4}$ where the density n is in units of 10^{10} cm⁻². The strong agreement between CHNC and the Zhu data is perhaps fortuitous since the results are quite sensitivity to the $d^2/d\zeta^2$ calculation to the energy differences $\Delta E = E_c(\zeta = 1) - E_c(\zeta = 0)$ and the form of the polarization factor $P(r_s, \zeta)$. The CHNC is calibrated to the Tenatar-Ceperley QMC which differs somewhat from the Attaccalite data. We have also plotted two CHNC curves where (see Eq.2) the term $r_s^2 \partial^2 \epsilon_{xc}/\partial \zeta^2$ has been modified by $\pm 2\%$. Clearly, errors in converting to r_s , modification of exchange-correlation gradients by well-width effects and the presence of impurities etc., can produce such a change. The bottom panel (Fig. 2) shows the comparison against r_s .

Zhu et al. report a ζ dependence, but now they consider that the finiteness of the 2-D layer and orbital effects cannot be ignored in analysing field-dependent data [28]. As pointed out via the $\pm 2\%$ plots in Fig.2, the sensitivity of χ_P/χ_s to small errors in the xc-energy gradient is also important. (Discussion of these and other data for m^* and g^* , of Zhu's thesis [6] will await their publication).

In our results, χ_s/χ_P is less sensitive to ζ at high density, and very sensitive to ζ at low density, approaching the *para* \rightarrow *ferro* transition. In fact, the second derivative in Eq.2 diverges at $\zeta = 1$.

A very different experimental picture is found in Si-2DESs [7]. The CHNC results for the coupled 2-valley 2DES are shown in Fig. 3. The top panel compares the $m^*g^* = \chi_{cm}/\chi_P$ obtained from experiment and the coupled-mode analysis (the LFFS used are for the spin-spin response). The inset shows the shift of the simple uncoupled-valley curve to higher densities when the valley coupling is introduced. The conversion between density and r_s is discussed in ref. [3].

The middle panel (fig. 3) shows the m^* calculated from the finite-T analysis, with the sharp rise occurring at $r_s \sim 5.4$, i.e., density $n_{cv} = 1 \times 10^{11} / \text{cm}^2$. The inset shows the lack of ζ dependence in m^* for three densities. This is because the physics is dominated by singlet interactions, as in the ambi-spin phase reported earlier [1]. The lower panel of Fig. 3 shows the flat g^* of the coupled-valley fluid, while the inset shows the usual increase of g^* in the uncoupled system as the density is reduced.

Conclusion– We have presented results for the effective mass m^* , and the Landé g^* factor of 2-D electron fluids, using an analytic method. Our results suggest that exchange effects dominate as r_s increases in 1-valley 2D system, enhancing g^* when the one-valley spin-response diverges. Correlation effects outweigh exchange in 2-valley systems where m^* is strongly enhanced and only weakly dependent on ζ . The tendency to form singlets already noted in the single 2DES [25] becomes stronger in the 2-valley 2DES where a coupled-valley state is formed. Our theoretical results depend only on the $\epsilon_{xc}(r_s, \zeta, T)$ used in calculating ζ and Tderivatives, and invoke no fit parameters specific to this problem. However, the inter-valley energy F_{uv} was approximated via the $F_{12}(\zeta = 0)$ of the one-valley inter-spin energy. As already noted, χ/χ_0 is quite sensitive to the evaluation of $d^2/d\zeta^2$. However, the agreement of the present model with experiment may prove useful in understanding the experimental results.

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We thank Peter Coleridge, Wally Geldart, François Perrot, Sasha Shashkin, Horst Stormer and Jun Zhu for their comments and correspondence.

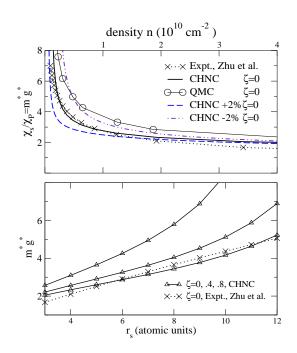


Fig. 2 – The spin-susceptibility enhancement $\chi_s/\chi_P = m^*g^*$ in the 2DES. Top panel: comparison of experiment [6], QMC [2]. and CHNC. Curves marked $\pm 2\%$ are CHNC predictions if the exchange-correlation contribution $r_s^2 \partial^2 \epsilon_{xc}/\partial \zeta^2$ is modified by $\pm 2\%$. Bottom panel: CHNC results for m^*g^* for 3 spin-polarization ζ , and the experimental $\zeta=0$ data, plotted against r_s .

REFERENCES

- [1] DHARMA-WARDANA M. W. C. ET AL., Phys. Rev. Lett., 90 (2003) 136601
- [2] ATTACCALITE C. ET AL., Phys. Rev. Lett., 88 (2002) 256601
- [3] ANDO T. ET AL., Rev. Mod. Phys., 54 (1982) 437
 (Conversion of n to r_s: GaAs-2DES, as in Zhu et al. [6], Si-2DES, 2-valleys, Ando et al. provide two eqns. Our first-principles model [Phys. Rev. B, 65, 165339 (2002)] of Si/SiO₂ shows that the 37% lattice mismatch between Si and SiO₂ creates an amorphous Si layer between the crystalline c-Si and the suboxide layers. Thus the first formula of Ando et al. holds. See Ref. [4])
- [4] DHARMA-WARDANA M. W. C. ET AL., cond-mat/0402253,
- [5] KRAVCHENKO S. V. and SARACHIK M. P., Rep. Prog. Phys., 67 (2004) 1.
- [6] ZHU J. ET AL., Phys. Rev. Lett., 90 (2003) 56805 ZHU J., Ph. D thesis (Columbia Univ.) 2003
- [7] SHASHKIN A. A. ET AL., Phys. Rev. Lett., 91 (2003) 46403
- [8] CONTI S. and G. SENATORE G., i Europhys. Lett., 361996695
- [9] SANTORO G. E. ET AL., Phys. Rev. B, 37 (1988) 4813
- [10] MORAWETZ K., cond-mat/0210168, ASGARI R. ET AL., cond-mat/0401289,
- [11] GALITSKI V. M. ET AL., cond-mat/0308203,
- [12] KWON Y. ET AL., Phys. Rev. B, 50 (1994) 1684
- [13] DHARMA-WARDANA M. W. C. and PERROT F., , Phys. Rev. Lett., 84 (2000) 959
- [14] PERROT F. ET AL., Phys. Rev. B, 62 (2000) 16536

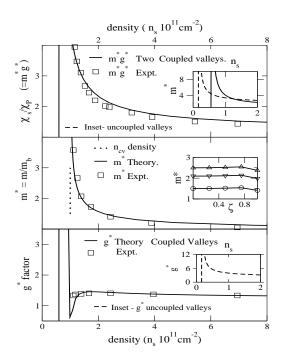


Fig. 3 – Comparison of experiment [7] and theory for the 2-valley 2DES in Si-MOSFETs. The top panel shows m^*g^* , while the inset shows the shift of theoretical m^*g^* curve to higher densities due to mode coupling. The middle panel shows m^* which rises steeply at the onset of the spin-singlet coupled-valley state at $n_{cv}=1\times10^{11}/\text{cm}^2$. The inset shows the insensitivity of m^* to the spin-polarization for three densities. The bottom panel compares the experimental g^* with theory.

- [15] PERROT F. ET AL., Phys. Rev. Lett., 87 (2001) 206404
- [16] DHARMA-WARDANA M. W. C. and PERROT F., Phys. Rev. B, 66 (2002) 14110
- [17] HOHENBERG P. AND KOHN W., Phys. Rev., 136B (1964) 864
- [18] VAN LEEUWEN J. M. J. ET AL., *Physica*, **25** (1959) 792
- [19] F. LADO F., J. Chem. Phys., 47 (1967) 5369
- [20] KHANH N. Q. AND TOTSUJI H., Solid. St. Com., 129200437
- [21] GELDART D. J. W., (private communication)
- [22] P. VASHISHTA ET AL, Phys. Rev. B, 10 (1974) 5108
- [23] PUDALOV ET AL., cond-mat/0110160v2,
- [24] PUDALOV ET AL., cond-mat/0104347,
- [25] DHARMA-WARDANA M. W. C. and PERROT F., Europhys. Lett., 632003660; cond-mat/0304034,
- [26] (Unlike in ref. [9] we use the same form, $1 v_{cou}(1 G_v)$, for both symmetric and antisymmetric LFFs, using the same write up for both. Thus G_- of ref. [9] is our $G_v 1$ for the spin- χ , while their G_+ is our G_v for the density- χ .)
- [27] COLERIDGE P. ET AL., Surface Science, 361/362 (1996) 560
- [28] ZHU J. and STORMER H., (private com.) TUTUC E. ET AL., arXiv:cond-mat/0301027v2